FAIRCHILD SEMICONDUCTOR™

May 1998

74LVQ240
Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

General Description

The LVQ240 is an inverting octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density.

Features

- Ideal for low power/low noise 3.3V applications
- Implements patented EMI reduction circuitry
- Available in SOIC JEDEC, SOIC EIAJ, and QSOP packages
- Guaranteed simultaneous switching noise level and dynamic threshold performance
- Improved latch-up immunity
- Guaranteed incident wave switching into 75Ω
- 4 kV minimum ESD immunity

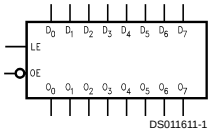
Ordering Code:

Order Number	Package Number	Package Description
74LVQ240SC	M20B	20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
74LVQ240SJ	M20D	20-Lead Molded Shrink Small Outline Package, SOIC, EIAJ
74LVQ240QSC	MQA20	20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC

Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.

Logic Symbol

IEEE/IEC



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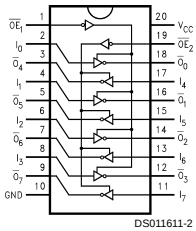
Pin Descriptions

Pin Names	Description
$\overline{OE}_1$, $\overline{OE}_2$	3-STATE Output Enable Inputs
I_0–I_7	Inputs
$\overline{O}_0$–$\overline{O}_7$	Outputs

Connection Diagram

Pin Assignment, SOIC and QSOP



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Truth Tables

Inputs		Outputs
$\overline{OE}_1$	I_n	(Pins 12, 14, 16, 18)
L	L	H
L	H	L
H	X	Z

Inputs		Outputs
$\overline{OE}_2$	I_n	(Pins 3, 5, 7, 9)
L	L	H
L	H	L
H	X	Z

H = HIGH Voltage Level L = LOW Voltage Level
X = Immaterial Z = High Impedance

Absolute Maximum Ratings (Note 1)

Supply Voltage (V_{CC})	−0.5V to +7.0V
DC Input Diode Current (I_{IK})	
V_I = −0.5V	−20 mA
V_I = V_{CC} + 0.5V	+20 mA
DC Input Voltage (V_I)	−0.5V to V_{CC} + 0.5V
DC Output Diode Current (I_{OK})	
V_O = −0.5V	−20 mA
V_O = V_{CC} + 0.5V	+20 mA
DC Output Voltage (V_O)	−0.5V to V_{CC} + 0.5V
DC Output Source or Sink Current (I_O)	±50 mA
DC V_{CC} or Ground Current (I_{CC} or I_{GND})	±400 mA
Storage Temperature (T_{STG})	−65°C to +150°C
DC Latch-Up Source or Sink Current	±300 mA

Recommended Operating Conditions (Note 2)

Supply Voltage (V_{CC})	2.0V to 3.6V
Input Voltage (V_I)	0V to V_{CC}
Output Voltage (V_O)	0V to V_{CC}
Operating Temperature (T_A)	−40°C to +85°C
Minimum Input Edge Rate (ΔV/Δt)	
V_{IN} 0.8V to 2.0V	
V_{CC} @ 3.0V	125 mV/ns

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V_{CC} (V)	T_A = +25°C	T_A = −40°C to +85°C		Units	Conditions
			Typ	Guaranteed Limits			
V_{IH}	Minimum High Level Input Voltage	3.0	1.5	2.0	2.0	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{IL}	Maximum Low Level Input Voltage	3.0	1.5	0.8	0.8	V	V_{OUT} = 0.1V or V_{CC} − 0.1V
V_{OH}	Minimum High Level Output Voltage	3.0	2.99	2.9	2.9	V	I_{OUT} = −50 μA
		3.0		2.58	2.48	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OH} = −12 mA
V_{OL}	Maximum Low Level Output Voltage	3.0	0.002	0.1	0.1	V	I_{OUT} = 50 μA
		3.0		0.36	0.44	V	V_{IN} = V_{IL} or V_{IH} (Note 3) I_{OL} = 12 mA
I_{IN}	Maximum Input Leakage Current	3.6		±0.1	±1.0	μA	V_I = V_{CC}, GND
I_{OLD}	Minimum Dynamic Output Current (Note 4)	3.6			36	mA	V_{OLD} = 0.8V Max (Note 5)
I_{OHD}		3.6			−25	mA	V_{OHD} = 2.0V Min (Note 5)
I_{CC}	Maximum Quiescent Supply Current	3.6		4.0	40.0	μA	V_{IN} = V_{CC} or GND
I_{OZ}	Maximum 3-STATE Leakage Current	3.6		±0.25	±2.5	μA	V_I (OE) = V_{IL}, V_{IH} V_I = V_{CC}, GND V_O = V_{CC}, GND
V_{OLP}	Quiet Output Maximum Dynamic V_{OL}	3.3	0.4	0.8		V	(Notes 6, 7)
V_{OLV}	Quiet Output Minimum Dynamic V_{OL}	3.3	−0.4	−0.8		V	(Notes 6, 7)
V_{IHD}	Maximum High Level Dynamic Input Voltage	3.3	1.6	2.0		V	(Notes 6, 8)
V_{ILD}	Maximum Low Level Dynamic Input Voltage	3.3	1.6	0.8		V	(Notes 6, 8)

Note 3: All outputs loaded; thresholds on input associated with output under test.

Note 4: Maximum test duration 2.0 ms, one output loaded at a time.

Note 5: Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed for 74LVQ.

Note 6: Worst case package.

Note 7: Max number of outputs defined as (n). Data Inputs are driven 0V to 3.3V. One output @ GND.

Note 8: Max number of Data Inputs (n) switching. n−1 Inputs switching 0V to 3.3V. Input-under-test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f = 1 MHz.

AC Electrical Characteristics

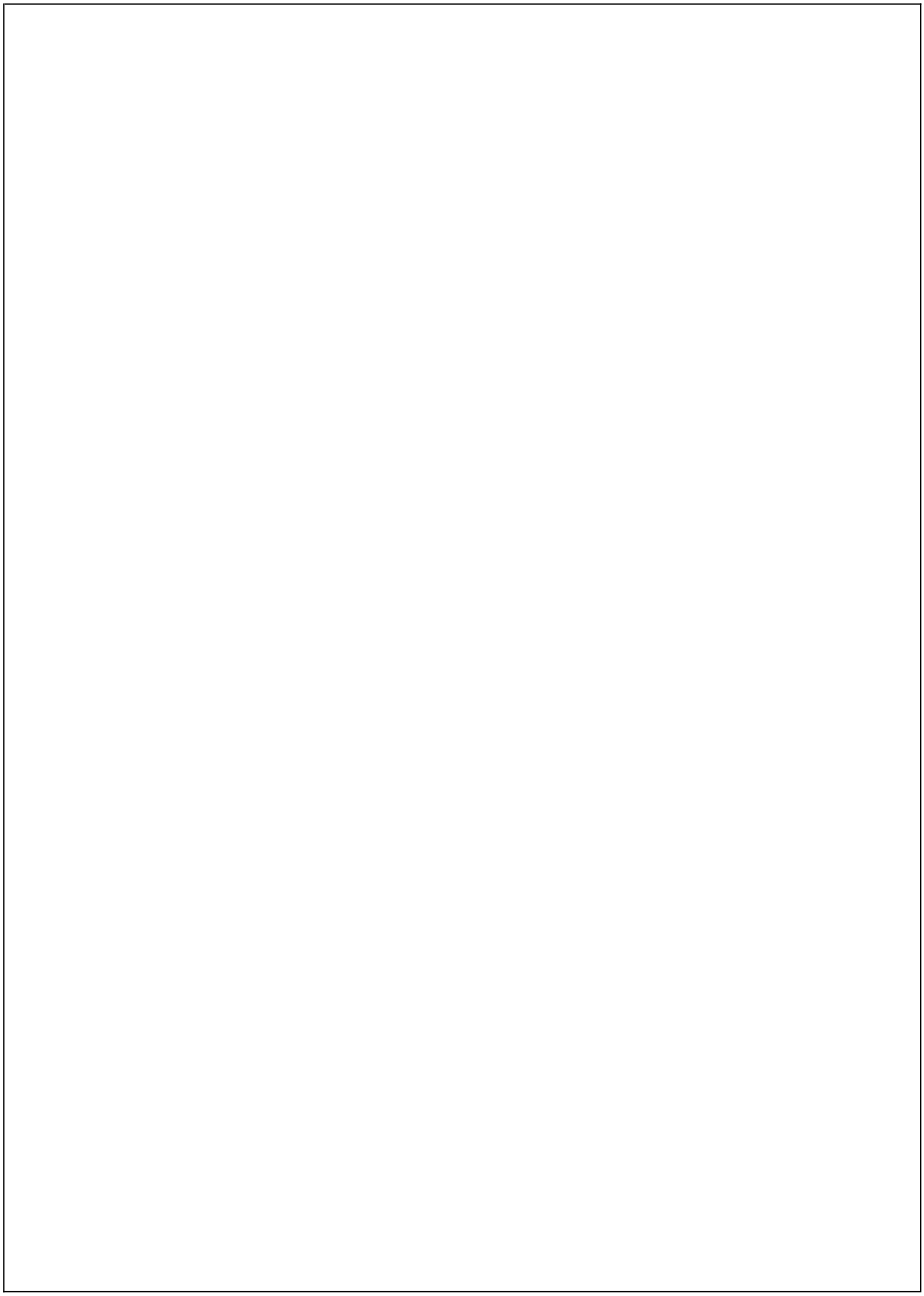
Symbol	Parameter	V_{CC} (V)	$T_A = +25^{\circ}C$, $C_L = 50$ pF			$T_A = -40^{\circ}C$ to $+85^{\circ}C$, $C_L = 50$ pF		Units
			Min	Typ	Max	Min	Max	
t_{PHL}	Propagation Delay	2.7	2.0	8.4	14.0	2.0	15.0	ns
t_{PLH}	Data to Output	3.3 ±0.3	2.0	7.0	10.0	2.0	10.5	
t_{PZL}	Output Enable Time	2.7	2.5	9.6	16.9	2.5	18.0	ns
t_{PZH}		3.3±0.3	2.5	8.0	12.0	2.5	12.5	
t_{PHZ}	Output Disable Time	2.7	1.0	10.2	19.0	1.0	20.0	ns
t_{PLZ}		3.3 ±0.3	1.0	8.5	13.5	1.0	14.0	
t_{OSHL}	Output to Output Skew	2.7		1.0	1.5		1.5	ns
t_{OSLH}	Data to Output (Note 9)	3.3 ±0.3		1.0	1.5		1.5	

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}). Parameter guaranteed by design.

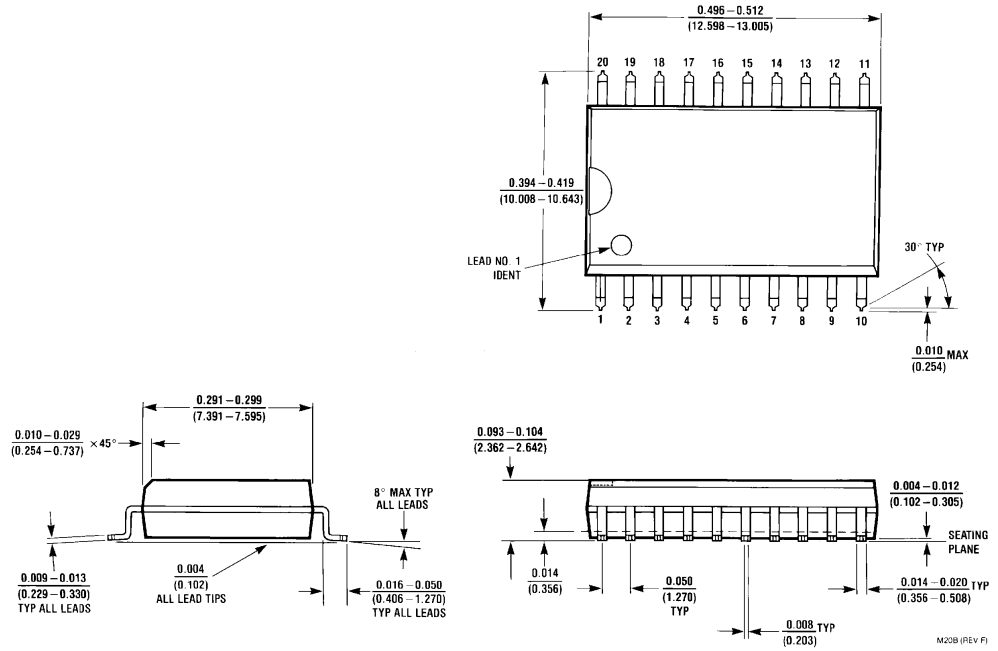
Capacitance

Symbol	Parameter	Typ	Units	Conditions
C_{IN}	Input Capacitance	4.5	pF	V_{CC} = Open
C_{PD} (Note 10)	Power Dissipation Capacitance	70	pF	V_{CC} = 3.3V

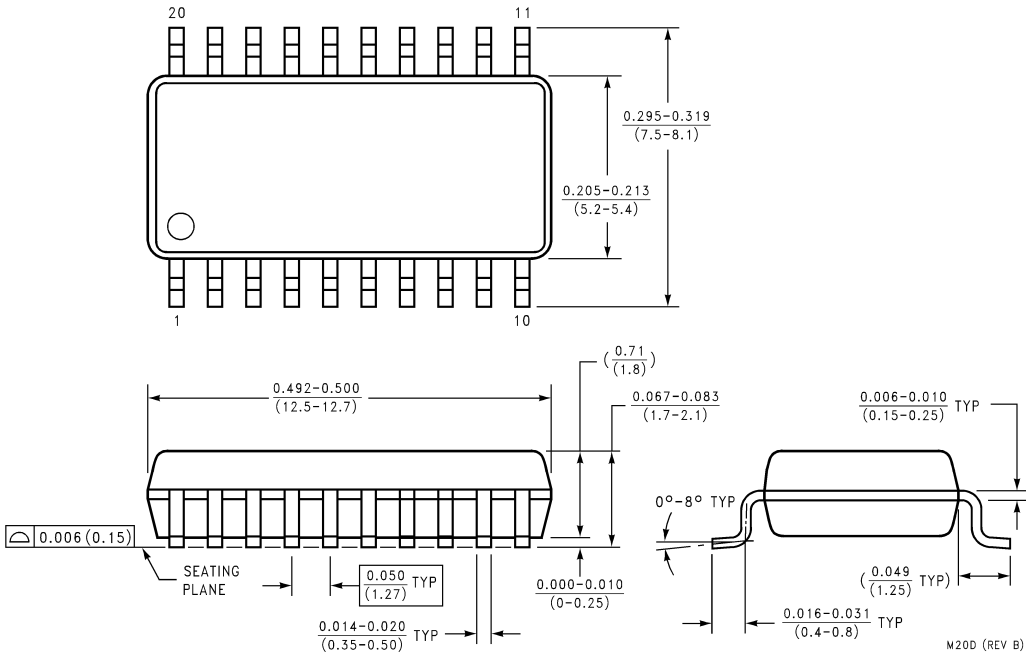
Note 10: C_{PD} is measured at 10 MHz.



Physical Dimensions inches (millimeters) unless otherwise noted

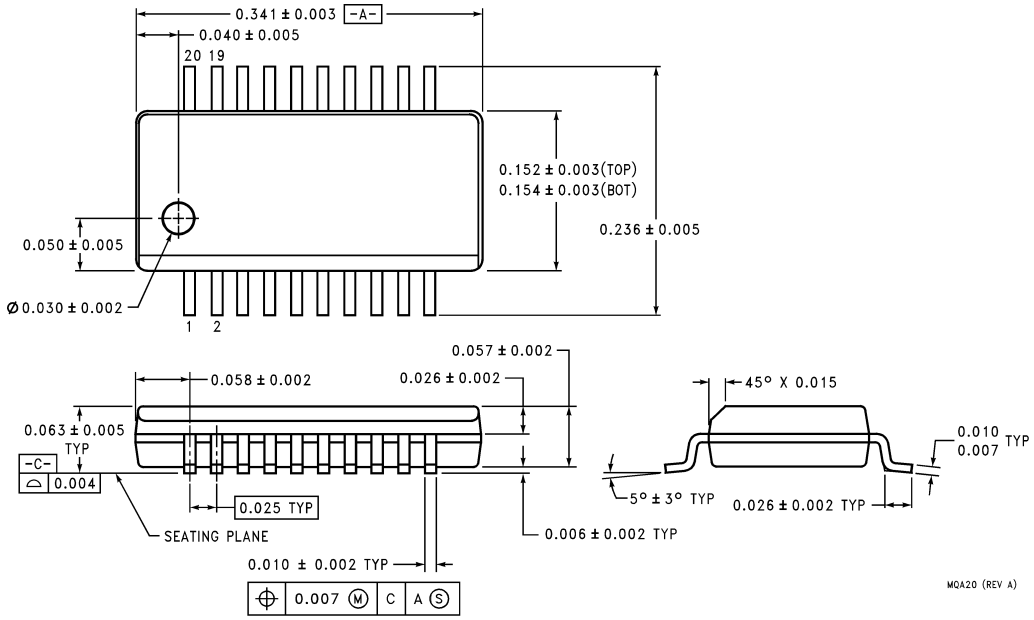


20-Lead (0.300" Wide) Molded Small Outline Package, SOIC, JEDEC
Package Number M20B



20-Lead Molded Shrink Small Outline Package, SOIC, EIAJ
Package Number M20D

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



20-Lead (0.150" Wide) Molded Shrink Small Outline Package, SSOP, JEDEC
(also known as QSOP)
Package Number MQA20

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